E·XFL



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What is "Embedded - Microcontrollers"?

"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "<u>Embedded -</u> <u>Microcontrollers</u>"

Details

Product Status	Discontinued at Digi-Key
Core Processor	CIP-51 8051
Core Size	8-Bit
Speed	50MHz
Connectivity	I ² C, SMBus, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, POR, PWM, WDT
Number of I/O	21
Program Memory Size	16KB (16K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	2.25K x 8
Voltage - Supply (Vcc/Vdd)	2.2V ~ 3.6V
Data Converters	A/D 13x10/12b SAR; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	24-SSOP (0.154", 3.90mm Width)
Supplier Device Package	24-QSOP
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm8bb31f16g-a-qsop24r

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Timers (Timer 0, Timer 1, Timer 2, Timer 3, Timer 4, and Timer 5)

Several counter/timers are included in the device: two are 16-bit counter/timers compatible with those found in the standard 8051, and the rest are 16-bit auto-reload timers for timing peripherals or for general purpose use. These timers can be used to measure time intervals, count external events and generate periodic interrupt requests. Timer 0 and Timer 1 are nearly identical and have four primary modes of operation. The other timers offer both 16-bit and split 8-bit timer functionality with auto-reload and capture capabilities.

Timer 0 and Timer 1 include the following features:

- Standard 8051 timers, supporting backwards-compatibility with firmware and hardware.
- Clock sources include SYSCLK, SYSCLK divided by 12, 4, or 48, the External Clock divided by 8, or an external pin.
- · 8-bit auto-reload counter/timer mode
- 13-bit counter/timer mode
- 16-bit counter/timer mode
- Dual 8-bit counter/timer mode (Timer 0)

Timer 2, Timer 3, Timer 4, and Timer 5 are 16-bit timers including the following features:

- · Clock sources for all timers include SYSCLK, SYSCLK divided by 12, or the External Clock divided by 8
- · LFOSC0 divided by 8 may be used to clock Timer 3 and Timer 4 in active or suspend/snooze power modes
- Timer 4 is a low-power wake source, and can be chained together with Timer 3
- 16-bit auto-reload timer mode
- Dual 8-bit auto-reload timer mode
- · External pin capture
- · LFOSC0 capture
- Comparator 0 capture
- Configurable Logic output capture

Watchdog Timer (WDT0)

The device includes a programmable watchdog timer (WDT) running off the low-frequency oscillator. A WDT overflow forces the MCU into the reset state. To prevent the reset, the WDT must be restarted by application software before overflow. If the system experiences a software or hardware malfunction preventing the software from restarting the WDT, the WDT overflows and causes a reset. Following a reset, the WDT is automatically enabled and running with the default maximum time interval. If needed, the WDT can be disabled by system software or locked on to prevent accidental disabling. Once locked, the WDT cannot be disabled until the next system reset. The state of the RST pin is unaffected by this reset.

The Watchdog Timer has the following features:

- · Programmable timeout interval
- · Runs from the low-frequency oscillator
- · Lock-out feature to prevent any modification until a system reset

3.6 Communications and Other Digital Peripherals

Universal Asynchronous Receiver/Transmitter (UART0)

UART0 is an asynchronous, full duplex serial port offering modes 1 and 3 of the standard 8051 UART. Enhanced baud rate support allows a wide range of clock sources to generate standard baud rates. Received data buffering allows UART0 to start reception of a second incoming data byte before software has finished reading the previous data byte.

The UART module provides the following features:

- · Asynchronous transmissions and receptions
- Baud rates up to SYSCLK/2 (transmit) or SYSCLK/8 (receive)
- 8- or 9-bit data
- · Automatic start and stop generation
- · Single-byte buffer on transmit and receive

4.1.2 Power Consumption

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit	
Digital Core Supply Current							
Normal Mode-Full speed with code	I _{DD}	F _{SYSCLK} = 49 MHz ²	_	TBD	TBD	mA	
		F _{SYSCLK} = 24.5 MHz ²	_	4.5	TBD	mA	
		F _{SYSCLK} = 1.53 MHz ²	_	615	TBD	μA	
		F _{SYSCLK} = 80 kHz ³	—	155	TBD	μA	
Idle Mode-Core halted with peripherals rupping	I _{DD}	F _{SYSCLK} = 49 MHz ²	—	TBD	TBD	mA	
		F _{SYSCLK} = 24.5 MHz ²	—	2.8	TBD	mA	
		F _{SYSCLK} = 1.53 MHz ²		455	TBD	μA	
		F _{SYSCLK} = 80 kHz ³	_	145	TBD	μA	
Suspend Mode-Core halted and	I _{DD}	LFO Running	—	125	TBD	μA	
Supply monitor off.		LFO Stopped	—	120	TBD	μA	
Snooze Mode-Core halted and	I _{DD}	LFO Running	—	26	TBD	μA	
high frequency clocks stopped. Regulator in low-power state, Sup- ply monitor off.		LFO Stopped	_	21	TBD	μA	
Stop Mode—Core halted and all clocks stopped,Internal LDO On, Supply monitor off.	I _{DD}		_	120	TBD	μA	
Shutdown Mode—Core halted and all clocks stopped,Internal LDO Off, Supply monitor off.	I _{DD}		_	0.2	_	μA	
Analog Peripheral Supply Currents							
High-Frequency Oscillator 0	I _{HFOSC0}	Operating at 24.5 MHz,	_	55		μA	
		T _A = 25 °C					
High-Frequency Oscillator 1	I _{HFOSC1}	Operating at 49 MHz,	_	TBD	_	μA	
		T _A = 25 °C					
Low-Frequency Oscillator	I _{LFOSC}	Operating at 80 kHz,	—	5		μA	
		T _A = 25 °C					
ADC0 ⁴	I _{ADC}	TBD	_	TBD	TBD	μA	
Internal ADC0 Reference ⁵	I _{VREFFS}	Normal Power Mode	—	680	TBD	μA	
		Low Power Mode	_	160	TBD	μA	
On-chip Precision Reference	ference I _{VREFP}		—	75	—	μA	
Temperature Sensor	ITSENSE		_	75	120	μA	
Digital-to-Analog Converters (DAC0, DAC1) ⁶	I _{DAC}		-	125	_	μA	

Table 4.2. Power Consumption

4.1.4 Flash Memory

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units
Write Time ^{1 ,2}	t _{WRITE}	One Byte,	19	20	21	μs
		F _{SYSCLK} = 24.5 MHz				
Erase Time ^{1 ,2}	t _{ERASE}	One Page,	5.2	5.35	5.5	ms
		F _{SYSCLK} = 24.5 MHz				
V _{DD} Voltage During Programming ³	V _{PROG}		2.2		3.6	V
Endurance (Write/Erase Cycles)	N _{WE}		20k	100k	_	Cycles

Table 4.4. Flash Memory

Note:

1. Does not include sequencing time before and after the write/erase operation, which may be multiple SYSCLK cycles.

2. The internal High-Frequency Oscillator 0 has a programmable output frequency, which is factory programmed to 24.5 MHz. If user firmware adjusts the oscillator speed, it must be between 22 and 25 MHz during any flash write or erase operation. It is recommended to write the HFO0CAL register back to its reset value when writing or erasing flash.

3. Flash can be safely programmed at any voltage above the supply monitor threshold (V_{VDDM}).

4. Data Retention Information is published in the Quarterly Quality and Reliability Report.

4.1.5 Power Management Timing

Table 4.5. Power Management Timing

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Idle Mode Wake-up Time	t _{IDLEWK}		2	_	3	SYSCLKs
Suspend Mode Wake-up Time	t _{SUS-}	SYSCLK = HFOSC0	—	170	_	ns
	PENDWK	CLKDIV = 0x00				
Snooze Mode Wake-up Time	t _{SLEEPWK}	SYSCLK = HFOSC0	—	12	_	μs
		CLKDIV = 0x00				

4.1.8 Crystal Oscillator

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Crystal Frequency	f _{XTAL}		0.02	_	25	MHz
Crystal Drive Current	I _{XTAL}	XFCN = 0	—	0.5	—	μA
		XFCN = 1	—	1.5	_	μA
		XFCN = 2	—	4.8	_	μA
		XFCN = 3	—	14	—	μA
		XFCN = 4	_	40	_	μA
		XFCN = 5	_	120	_	μA
		XFCN = 6	_	550	_	μA
		XFCN = 7		2.6		mA

Table 4.8. Crystal Oscillator

Table 4.9. ADC

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit
Resolution	N _{bits}	bits 12 Bit Mode		12		
		10 Bit Mode		10		Bits
Throughput Rate	f _S	10 Bit Mode	_	_	1.125	Msps
(High Speed Mode)						
Throughput Rate	f _S	12 Bit Mode	_	_	300	ksps
(Low Power Mode)		10 Bit Mode	_	_	1.125	Msps
Tracking Time	t _{TRK}	High Speed Mode	230	_	_	ns
		Low Power Mode	450	_	—	ns
Power-On Time	t _{PWR}		1.2	_	_	μs
SAR Clock Frequency	f _{SAR}	High Speed Mode	_	_	18	MHz
		Low Power Mode	_	_	TBD	MHz
Conversion Time ¹	t _{CNV}	12-Bit Conversion,		0.7	1	μs
		SAR Clock =18 MHz,				
		System Clock = 49 MHz				
		10-Bit Conversion,	0.59			μs
		SAR Clock =18 MHz,				
		System Clock = 49 MHz				
Sample/Hold Capacitor	C _{SAR}	Gain = 1	_	5.2	_	pF
		Gain = 0.75	_	3.9	_	pF
		Gain = 0.5	_	2.6	_	pF
		Gain = 0.25	_	1.3	_	pF
Input Pin Capacitance	C _{IN}		_	20	_	pF
Input Mux Impedance	R _{MUX}		_	550	_	Ω
Voltage Reference Range	V _{REF}		1	_	V _{IO}	V
Input Voltage Range ²	V _{IN}	Gain = 1	0	_	V _{REF} / Gain	V
Power Supply Rejection Ratio	PSRR _{ADC}		_	TBD	_	dB
DC Performance			1	1		
Integral Nonlinearity	INL	12 Bit Mode	-1.4	TBD	+1.4	LSB
		10 Bit Mode	_	TBD	_	LSB
Differential Nonlinearity (Guaran-	DNL	12 Bit Mode	_	TBD	0.9	LSB
teed Monotonic)		10 Bit Mode	_	TBD	_	LSB
Offset Error	E _{OFF}	12 Bit Mode	-2	TBD	2	LSB
		10 Bit Mode	_	TBD	_	LSB

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit	
Offset Temperature Coefficient	TC _{OFF}		_	TBD	_	LSB/°C	
Slope Error	E _M	12 Bit Mode	_	TBD	TBD	%	
		10 Bit Mode	_	TBD	_	%	
Dynamic Performance 10 kHz Sine Wave Input 1 dB below full scale, Max throughput, using AGND pin							
Signal-to-Noise	SNR	12 Bit Mode	_	TBD	_	dB	
		10 Bit Mode	_	TBD	_	dB	
Signal-to-Noise Plus Distortion	SNDR	12 Bit Mode	TBD	TBD	_	dB	
		10 Bit Mode	_	TBD	_	dB	
Total Harmonic Distortion (Up to	THD	12 Bit Mode	_	TBD	_	dB	
5th Harmonic)		10 Bit Mode	_	TBD	_	dB	
Spurious-Free Dynamic Range	SFDR	12 Bit Mode	—	TBD	-	dB	
		10 Bit Mode	_	TBD	_	dB	

Note:

1. Conversion Time does not include Tracking Time. Total Conversion Time is:

Total Conversion Time = [RPT × (ADTK + NUMBITS + 1) × T(SARCLK)] + (T(ADCCLK) × 4)

where RPT is the number of conversions represented by the ADRPT field and ADCCLK is the clock selected for the ADC.

2. Absolute input pin voltage is limited by the V_{IO} supply.

4.1.11 Temperature Sensor

Parameter	Symbol	Test Condition	Min	Тур	Max	Unit		
Offset	V _{OFF}	T _A = 0 °C	_	TBD	_	mV		
Offset Error ¹	E _{OFF}	T _A = 0 °C	_	TBD	_	mV		
Slope	М		—	TBD	_	mV/°C		
Slope Error ¹	E _M			TBD	_	μV/°C		
Linearity			—	TBD	—	°C		
Turn-on Time			—	TBD	_	μs		
Note: 1. Represents one standard deviation from the mean.								

Parameter	Symbol	Symbol Test Condition		Тур	Max	Unit
Negative Hysteresis	HYS _{CP-}	CPHYN = 00	—	-1.5	_	mV
Mode 3 (CPMD = 11)		CPHYN = 01	—	-4	—	mV
		CPHYN = 10	—	-8	—	mV
		CPHYN = 11		-16	_	mV
Input Range (CP+ or CP-)	V _{IN}		-0.25	_	V _{IO} +0.25	V
Input Pin Capacitance	C _{CP}			7.5	_	pF
Internal Reference DAC Resolution	N _{bits}			6		bits
Common-Mode Rejection Ratio	CMRR _{CP}		—	70	-	dB
Power Supply Rejection Ratio	PSRR _{CP}		—	72	-	dB
Input Offset Voltage	V _{OFF}	T _A = 25 °C	-10	0	10	mV
Input Offset Tempco	TC _{OFF}		—	3.5	-	μV/°

4.1.14 Configurable Logic

Table 4.14. Configurable Logic

Parameter	Symbol	Test Condition	Min	Тур	Мах	Unit
Propagation Delay	t _{DLY}	Through single CLU	TBD	_	TBD	ns
Clocking Frequency	F _{CLK}	1 or 2 CLUs Cascaded	—	—	73.5	MHz
		3 or 4 CLUs Cascaded	—	_	36.75	MHz

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
28	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	
29	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	
30	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.10	
				CLU3A.9	
31	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
32	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	
Center	GND	Ground			

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
2	P0.0	Multifunction I/O	Yes	P0MAT.0	VREF
				INT0.0	
				INT1.0	
				CLU0A.8	
				CLU2A.8	
				CLU3B.8	
3	GND	Ground			
4	VDD / VIO	Supply Power Input			
5	RSTb /	Active-low Reset /			
	С2СК	C2 Debug Clock			
6	P3.0 /	Multifunction I/O /			
	C2D	C2 Debug Data			
7	P2.3	Multifunction I/O	Yes	P2MAT.3	DAC3
				CLU1B.15	
				CLU2B.15	
				CLU3A.15	
8	P2.2	Multifunction I/O	Yes	P2MAT.2	DAC2
				CLU1A.15	
				CLU2B.14	
				CLU3A.14	
9	P2.1	Multifunction I/O	Yes	P2MAT.1	DAC1
				CLU1B.14	
				CLU2A.15	
				CLU3B.15	
10	P2.0	Multifunction I/O	Yes	P2MAT.0	DAC0
				CLU1A.14	
				CLU2A.14	
				CLU3B.14	
11	P1.6	Multifunction I/O	Yes	P1MAT.6	ADC0.11
				CLU3OUT	CMP1P.5
				CLU0A.15	CMP1N.5
				CLU1B.12	
				CLU2A.12	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
12	P1.5	Multifunction I/O	Yes	P1MAT.5	ADC0.10
				CLU2OUT	CMP1P.4
				CLU0B.14	CMP1N.4
				CLU1A.13	
				CLU2B.13	
				CLU3B.11	
13	P1.4	Multifunction I/O	Yes	P1MAT.4	ADC0.9
				I2C0_SCL	CMP1P.3
				CLU0A.14	CMP1N.3
				CLU1A.12	
				CLU2B.12	
				CLU3B.10	
14	P1.3	Multifunction I/O	Yes	P1MAT.3	CMP1P.2
				I2C0_SDA	CMP1N.2
				CLU0B.13	
				CLU1B.11	
				CLU2B.11	
				CLU3A.13	
15	GND	Ground			
16	P1.2	Multifunction I/O	Yes	P1MAT.2	ADC0.8
				CLU0A.13	
				CLU1A.11	
				CLU2B.10	
				CLU3A.12	
				CLU3B.13	
17	P1.1	Multifunction I/O	Yes	P1MAT.1	ADC0.7
				CLU0B.12	
				CLU1B.10	
				CLU2A.11	
				CLU3B.12	
18	P1.0	Multifunction I/O	Yes	P1MAT.0	ADC0.6
				CLU0A.12	
				CLU1A.10	
				CLU2A.10	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
19	P0.7	Multifunction I/O	Yes	P0MAT.7	ADC0.5
				INT0.7	CMP0P.5
				INT1.7	CMP0N.5
				CLU1OUT	CMP1P.1
				CLU0B.11	CMP1N.1
				CLU1B.9	
				CLU3A.11	
20	P0.6	Multifunction I/O	Yes	P0MAT.6	ADC0.4
				CNVSTR	CMP0P.4
				INT0.6	CMP0N.4
				INT1.6	CMP1P.0
				CLU0A.11	CMP1N.0
				CLU1B.8	
				CLU3A.10	
21	P0.5	Multifunction I/O	Yes	P0MAT.5	ADC0.3
				INT0.5	CMP0P.3
				INT1.5	CMP0N.3
				UART0_RX	
				CLU0B.10	
				CLU1A.9	
22	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	
23	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.10	
				CLU3A.9	



Figure 6.4. EFM8BB3x-QSOP24 Pinout

Table 6.4. PIN Definitions for EFW8BB3X-QSOP	Table 6.4.	Pin Definitions	for EFM8BB3x	-QSOP24
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Pin	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
Number					
1	P0.3	Multifunction I/O	Yes	P0MAT.3	XTAL2
				EXTCLK	
				INT0.3	
				INT1.3	
				CLU0B.9	
				CLU2B.10	
				CLU3A.9	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
2	P0.2	Multifunction I/O	Yes	P0MAT.2	XTAL1
				INT0.2	ADC0.1
				INT1.2	CMP0P.1
				CLU0OUT	CMP0N.1
				CLU0A.9	
				CLU2B.8	
				CLU3A.8	
3	P0.1	Multifunction I/O	Yes	P0MAT.1	ADC0.0
				INT0.1	CMP0P.0
				INT1.1	CMP0N.0
				CLU0B.8	AGND
				CLU2A.9	
				CLU3B.9	
4	P0.0	Multifunction I/O	Yes	P0MAT.0	VREF
				INT0.0	
				INT1.0	
				CLU0A.8	
				CLU2A.8	
				CLU3B.8	
5	GND	Ground			
6	VDD / VIO	Supply Power Input			
7	RSTb /	Active-low Reset /			
	C2CK	C2 Debug Clock			
8	P3.0 /	Multifunction I/O /			
	C2D	C2 Debug Data			
9	P2.3	Multifunction I/O	Yes	P2MAT.3	DAC3
				CLU1B.15	
				CLU2B.15	
				CLU3A.15	
10	P2.2	Multifunction I/O	Yes	P2MAT.2	DAC2
				CLU1A.15	
				CLU2B.14	
				CLU3A.14	

Pin Number	Pin Name	Description	Crossbar Capability	Additional Digital Functions	Analog Functions
24	P0.4	Multifunction I/O	Yes	P0MAT.4	ADC0.2
				INT0.4	CMP0P.2
				INT1.4	CMP0N.2
				UART0_TX	
				CLU0A.10	
				CLU1A.8	

8. QFP32 Package Specifications

8.1 QFP32 Package Dimensions



Figure 8.1. QFP32 Package Drawing

Table 8.1. QFP32 Package Dimensions

Dimension	Min	Тур	Мах		
A	—	_	1.20		
A1	0.05	_	0.15		
A2	0.95	1.00	1.05		
b	0.30	0.37	0.45		
С	0.09	_	0.20		
D	9.00 BSC				
D1	7.00 BSC				
е	0.80 BSC				
E	9.00 BSC				
E1	7.00 BSC				
L	0.50 0.60 0.70				

8.2 QFP32 PCB Land Pattern



Figure 8.2. QFP32 PCB Land Pattern Drawing

Table 8.2.	QFP32 PCB	Land Pattern	Dimensions
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Dimension	Min	Мах		
C1	8.40	8.50		
C2	8.40	8.50		
E	0.80 BSC			
X1	0.55			
Y1	1.5			

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This Land Pattern Design is based on the IPC-7351 guidelines.

3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

5. The stencil thickness should be 0.125 mm (5 mils).

6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.

7. A No-Clean, Type-3 solder paste is recommended.

8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

9. QFN24 Package Specifications

9.1 QFN24 Package Dimensions



Figure 9.1. QFN24 Package Drawing

Dimension	Min	Тур	Мах		
A	0.8	0.85	0.9		
A1	0.00	—	0.05		
A2	—	0.65	—		
A3	0.203 REF				
b	0.15 0.2 0.25				
b1	0.25 0.3 0.35				
D	3.00 BSC				
E	3.00 BSC				

9.2 QFN24 PCB Land Pattern



Figure 9.2. QFN24 PCB Land Pattern Drawing

Table 9.2. QFN24 PCB Land Pattern Dimensions

Dimension	Min	Мах	
C1	3.00		
C2	3.00		
e	0.4 REF		
X1	0.20		
X2	1.80		
Y1	0.80		
Y2	1.80		
Y3	0.4		
f	2.50 REF		
с	0.25	0.35	

10.2 QSOP24 PCB Land Pattern



Figure 10.2. QSOP24 PCB Land Pattern Drawing

Table 10.2.	QSOP24 PCB Land Pattern Dimension	າຣ

Dimension	Min	Мах
С	5.20	5.30
E	0.635 BSC	
x	0.30	0.40
Y	1.50	1.60

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. This land pattern design is based on the IPC-7351 guidelines.

3. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

4. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.

5. The stencil thickness should be 0.125 mm (5 mils).

6. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.

7. A No-Clean, Type-3 solder paste is recommended.

8. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.